

MOS FET Relays

G3VM-61HR

Low 40-mΩ ON Resistance.

Higher power, 2.3-A switching with a 60-V load voltage, SOP package.

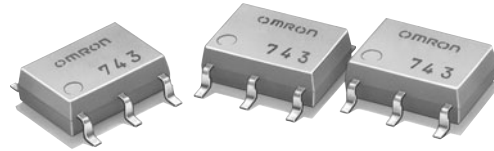
- Continuous load current of 2.3 A (connection C = 4.6 A).
- Dielectric strength of 1,500 Vrms between I/O.

RoHS compliant

⚠ Refer to "Common Precautions".

■ Application Examples

- Broadband systems
- Measurement devices
- Data loggers
- Industrial equipment



NEW

Note: The actual product is marked differently from the image shown here.

■ List of Models

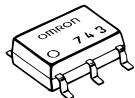
Contact form	Terminals	Load voltage (peak value) (See note.)	Model	Number per stick	Number per tape
SPST-NO	Surface-mounting terminals	60 V	G3VM-61HR	75	---
			G3VM-61HR(TR)	---	2,500

Note: The AC peak and DC value is given for the load voltage.

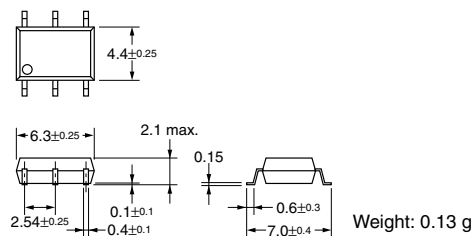
■ Dimensions

Note: All units are in millimeters unless otherwise indicated.

G3VM-61HR

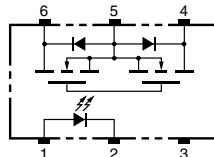


Note: The actual product is marked differently from the image shown here.



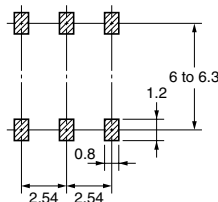
■ Terminal Arrangement/Internal Connections (Top View)

G3VM-61HR



■ Actual Mounting Pad Dimensions (Recommended Value, Top View)

G3VM-61HR

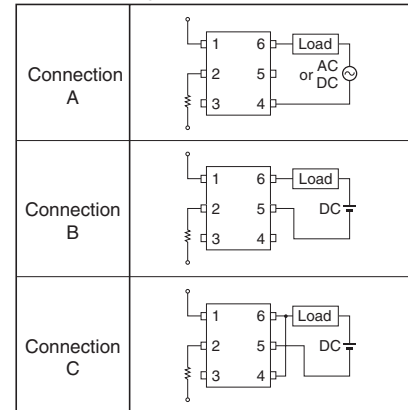


Absolute Maximum Ratings (Ta = 25°C)

Item			Symbol	Rating	Unit	Measurement Conditions
Input	LED forward current		I_F	30	mA	
	LED forward current reduction rate		$\Delta I_F/^{\circ}\text{C}$	−0.3	mA/ $^{\circ}\text{C}$	$T_a \geq 25^{\circ}\text{C}$
	LED reverse voltage		V_R	5	V	
	Connection temperature		T_j	125	$^{\circ}\text{C}$	
Output	Load voltage (AC peak/DC)		V_{OFF}	60	V	
	Continuous load current	Connection A	I_O	2.3	A	Connection A: AC peak/DC Connection B and C: DC
		Connection B		2.3		
		Connection C		4.6		
	ON current reduction rate	Connection A	$\Delta I_O/^{\circ}\text{C}$	−30.7	mA/ $^{\circ}\text{C}$	$T_a \geq 50^{\circ}\text{C}$
		Connection B		−30.7		
		Connection C		−61.3		
	Pulse on current		I_{op}	7	A	$t = 100 \text{ ms}$
	Connection temperature		T_j	125	$^{\circ}\text{C}$	
Dielectric strength between input and output (See note 1.)		V_{I-O}	1,500	V_{rms}	AC for 1 min	
Operating temperature		T_a	−40 to +85	$^{\circ}\text{C}$	With no icing or condensation	
Storage temperature		T_{stg}	−55 to +125	$^{\circ}\text{C}$	With no icing or condensation	
Soldering temperature (10 s)		---	260	$^{\circ}\text{C}$	10 s	

Note: 1. The dielectric strength between the input and output was checked by applying voltage between all pins as a group on the LED side and all pins as a group on the light-receiving side.

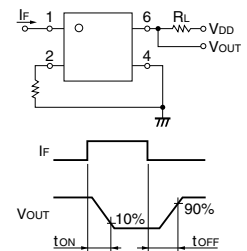
Connection Diagram



Electrical Characteristics (Ta = 25°C)

Item			Symbol	Minimum	Typical	Maximum	Unit	Measurement conditions
Input	LED forward voltage		V _F	1.18	1.33	1.48	V	I _F = 10 mA
	Reverse current		I _R	---	---	10	μA	V _R = 5 V
	Capacity between terminals		C _T	---	70	---	pF	V = 0, f = 1 MHz
	Trigger LED forward current		I _{FT}	---	0.4	3	mA	I _O = 100 mA
Output	Maximum resistance with output ON	Connection A	R _{ON}	---	0.04	0.07	Ω	I _F = 5 mA, I _O = 2 A, t < 1 s
		Connection B		---	0.02	0.04	Ω	I _F = 5 mA, I _O = 2 A, t < 1 s
		Connection C		---	0.01	---	Ω	I _F = 5 mA, I _O = 4 A, t < 1 s
	Current leakage when the relay is open		I _{LEAK}	---	---	10	nA	V _{OFF} = 60 V
Capacity between I/O terminals			C _{I-O}	---	0.8	---	pF	f = 1 MHz, V _s = 0 V
Insulation resistance			R _{I-O}	1,000	---	---	MΩ	V _{I-O} = 500 VDC, RoH ≤ 60%
Turn-ON time			t _{ON}	---	1.0	5.0	ms	I _F = 5 mA, R _L = 200 Ω, V _{DD} = 20 V (See note 2.)
Turn-OFF time			t _{OFF}	---	0.15	1.0	ms	

Note: 2. Turn-ON and Turn-OFF Times



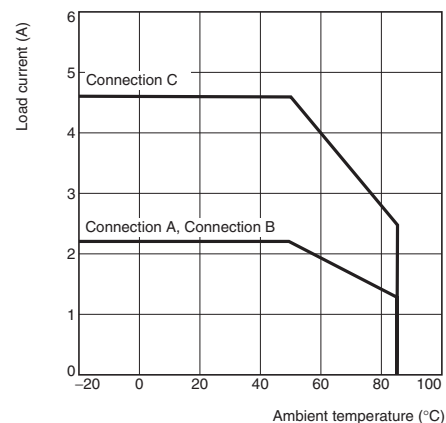
Recommended Operating Conditions

Use the G3VM under the following conditions so that the Relay will operate properly.

Item	Symbol	Minimum	Typical	Maximum	Unit
Load voltage (AC peak/DC)	V_{DD}	---	---	60	V
Operating LED forward current	I_F	5	7.5	20	mA
Continuous load current (AC peak/DC)	I_O	---	---	1.8	A
Operating temperature	T_a	-20	---	65	°C

Engineering Data

Load Current vs. Ambient Temperature G3VM-61HR



Safety Precautions

Refer to "Common Precautions" for all G3VM models.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9